

Embedded ReRAM is making good progress

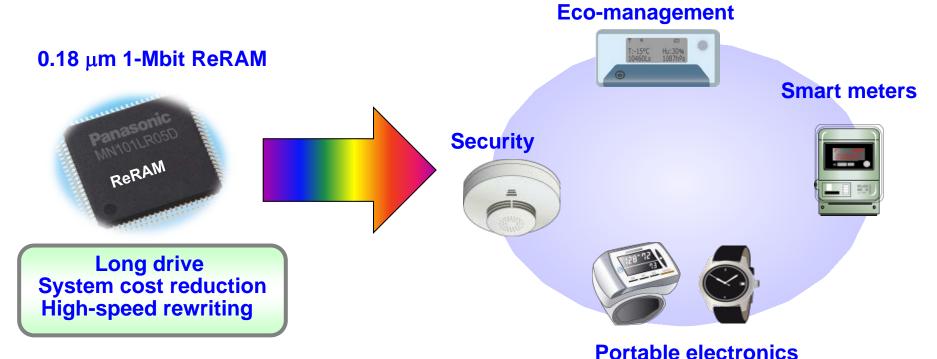
Zhiqiang Wei

Panasonic Semiconductor Solutions Co., Ltd



Application:

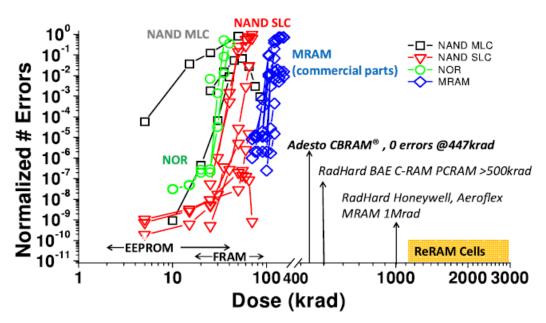
from Chip to Consumer Electronics



Flash Memory Summit 2015 Santa Clara, CA



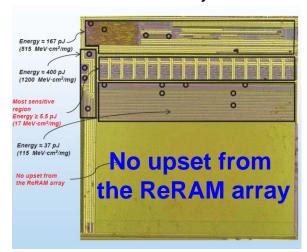
Radiation Hardness



Ref. Y. Gonzalez-Velo, et al, EDL, 35, 205, 2014

D. Chen, IEEE TRANSACTIONS ON NUCLEAR SCIENCE, 61, 3088, 2014

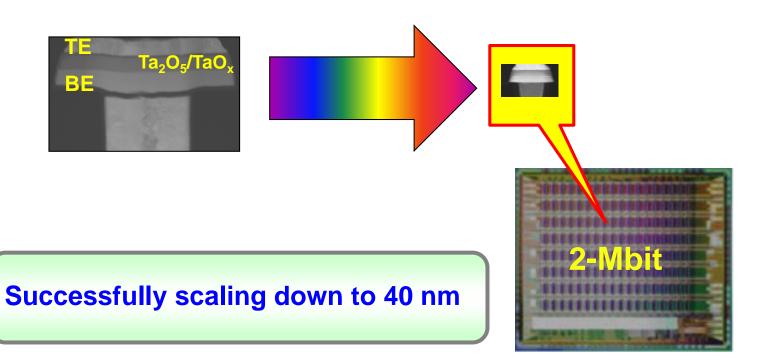
Panasonic TaOx Array





Process:

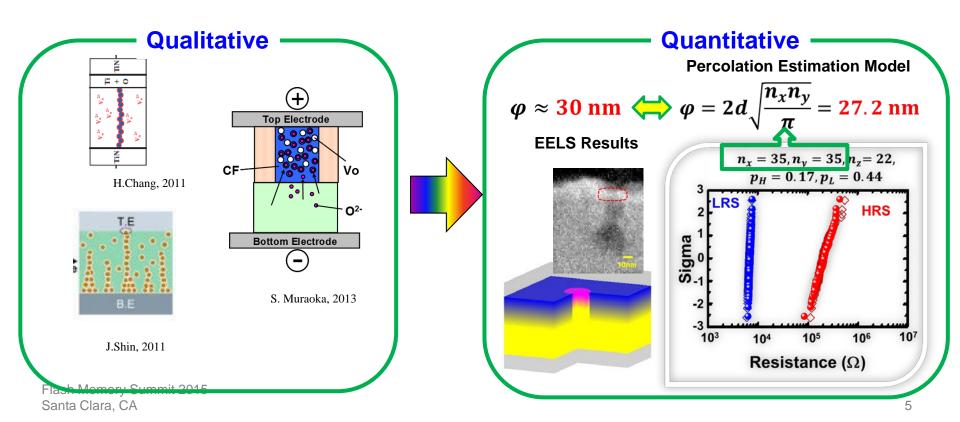
from 0.18 μ m to 40 nm





Filament:

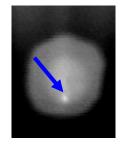
from Qualitative to Quantitative

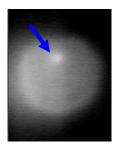


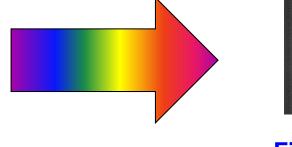


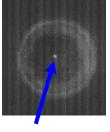
Filament:

from Everywhere to Centralizing









Filament

Side oxidation and other technologies centralize the filament



- ReRAM is already in our daily life.
- ReRAM is successfully scaling down to 40 nm.
- Filament dimensions can be estimated for each bit in memory array.
- Filament position is controllable.